



1.5V, 3V Strobe Applications

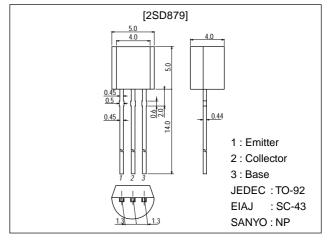
Features

- · In applications where two NiCd batteries are used to provide 2.4V, two 2SD879s are used.
- The charge time is approximately 1 second faster than that of germanium transistors.
- \cdot Less power dissipation because of low Collector-to-Emitter Voltage $V_{CE(sat)},$ permitting more flashes of light to be emitted.
- · Small package and large allowable collector dissipation (TO-92, PC=750mW).
- Large current capacity and highly resistant to breakdown.
- \cdot Excellent linearity of $h_{\mbox{\scriptsize FE}}$ in the region from low current to high current.

Package Dimensions

unit:mm

2003B



Specifications

Absolute Maximum Ratings at Ta = 25°C

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Parameter	Symbol	Conditions	Ratings	Unit	
Collector-to-Base Voltage	V _{CBO}		30	V	
Collector-to-Emitter Voltage	VCEX		20	V	
	VCEO		10	V	
Emitter-to-Base Voltage	V _{EBO}		6	V	
Collector Current	IC		3	Α	
Collector Current (Pulse)	I _{CP}	100ms single pulse	5	Α	
Collector Dissipation	PC		750	mW	
Junction Temperature	Tj		150	°C	
Storage Temperature	Tstg		-55 to +150	°C	

Electrical Characteristics at Ta = 25°C

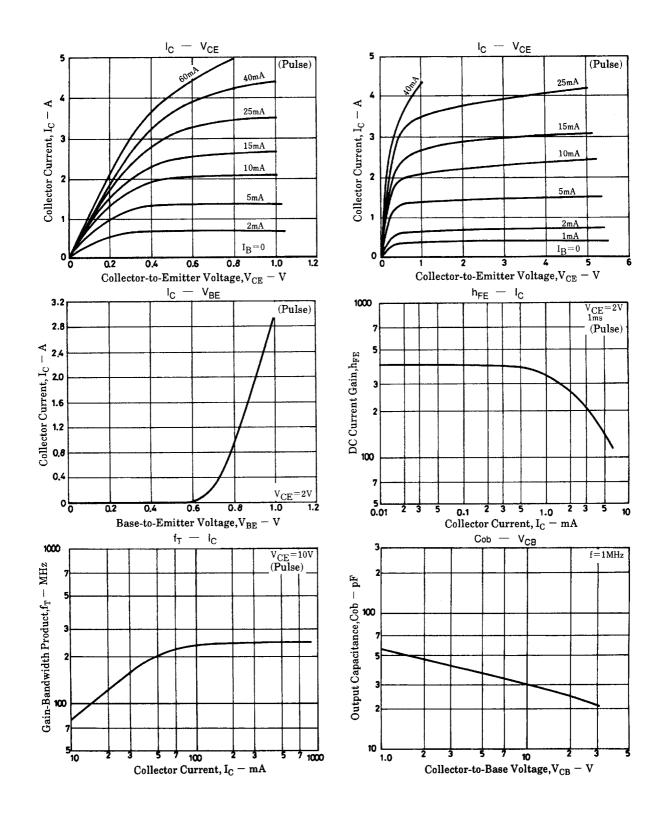
Parameter	Symbol	Conditions	Ratings			Unit
	Symbol		min	typ	max	l Oliit
Collector Cutoff Current	ICBO	V _{CB} =20V, I _E =0			1.0	μΑ
Emitter Cutoff Current	I _{EBO}	V _{EB} =4V, I _C =0			1.0	μΑ
DC Current Gain	h _{FE}	V _{CE} =2V, I _C =3A (pulse)	140	210		
Gain-Bandwidth Product	fT	V _{CE} =10V, I _C =50mA		200		MHz
Output Capacitance	C _{ob}	V _{CB} =10V, f=1MHz		30		pF
Collector-to-Emitter Saturation Voltage	VCE(sat)	I _C =3A, I _B =60mA (pulse)		0.3	0.4	V

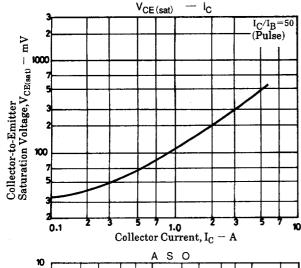
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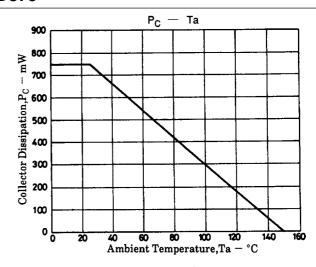
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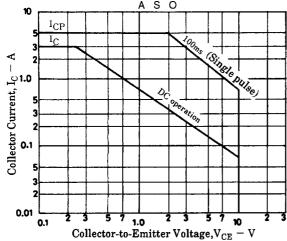
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	J Gill
Collector-to-Base Breakdown Voltage	V _(BR) CBO	I _C =10μA, I _E =0	30			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEX	I _C =1mA, V _{BE} =3V	20			V
	V(BR)CEO	I _C =1mA, R _{BE} =∞	10			V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	I _E =10μA, I _C =0	6			V

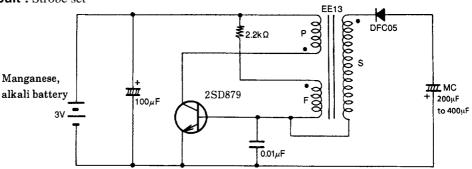




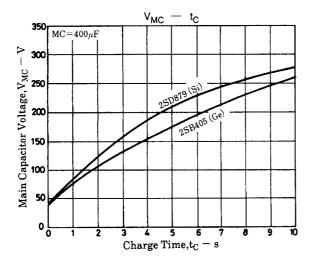


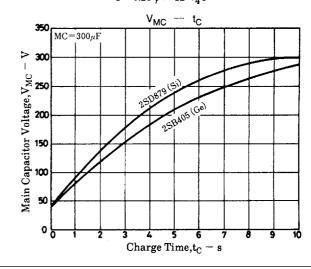


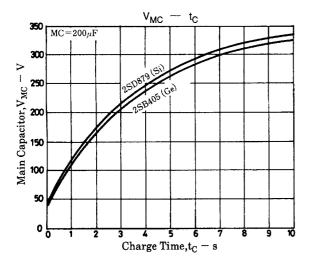
Sample Application Circuit: Strobe set



Core : EE13 (Kijima Wireless) Number of turns specified for transformer $~P:0.55~\phi\times10~3/_{4}T,~S:0.07~\phi\times1350T$ $~F:0.23~\phi\times12~3/_{4}T$







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